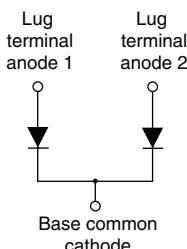


Schottky Rectifier

I_OR[®]


TO-244



FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free
- Designed and qualified for industrial level

DESCRIPTION

The 409CNQ... center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

PRODUCT SUMMARY	
I _{F(AV)}	400 A
V _R	135/150 V

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	400	A
V _{RRM}	Range	135/150	V
I _{FSM}	t _p = 5 µs sine	20 000	A
V _F	200 Apk, T _J = 125 °C (per leg)	0.75	V
T _J	Range	- 55 to 175	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	409CNQ135PbF	409CNQ150PbF	UNITS
Maximum DC reverse voltage	V _R			
Maximum working peak reverse voltage	V _{RWM}	135	150	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current per leg See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 129 °C, rectangular waveform		200	A
Maximum peak one cycle non-repetitive surge current per leg See fig. 7				400	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 5.5 A, L = 1 mH		15	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	A

409CNQ...PbF Series

Vishay High Power Products

Schottky Rectifier



ELECTRICAL SPECIFICATIONS

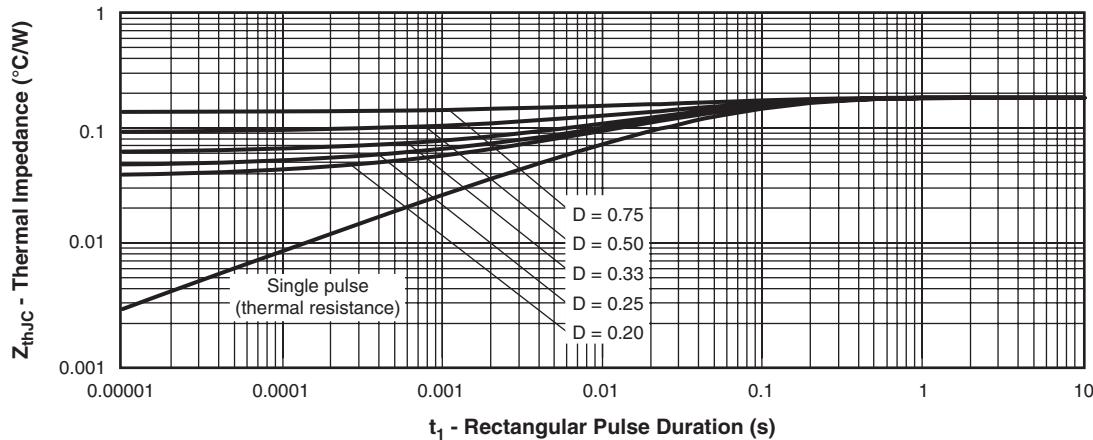
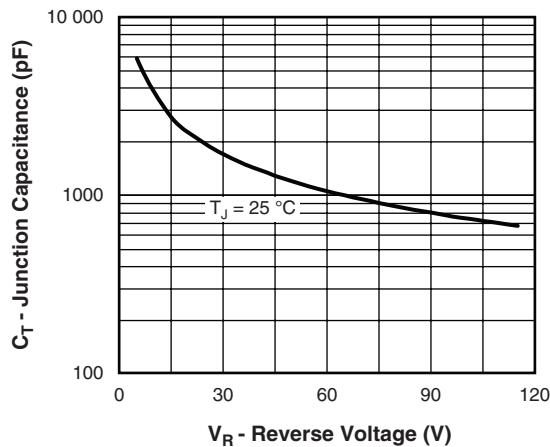
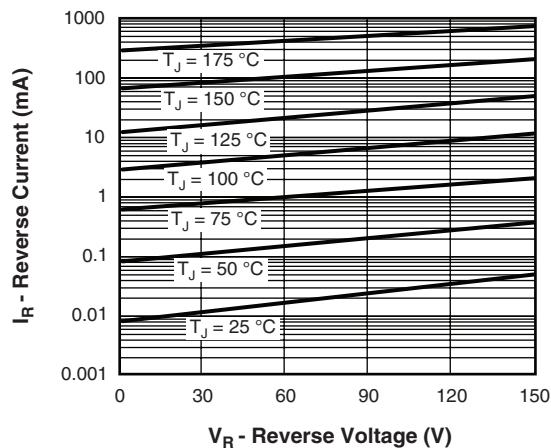
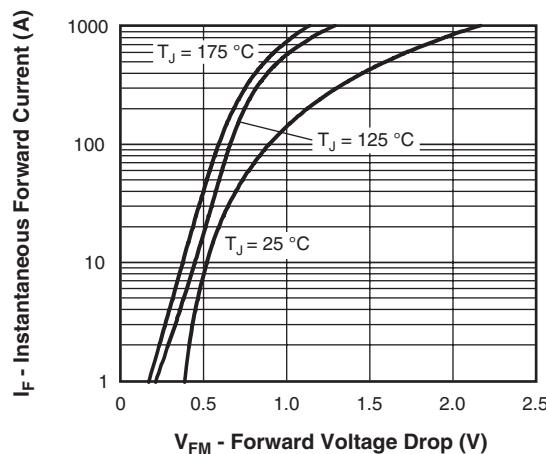
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop per leg See fig. 1	$V_{FM}^{(1)}$	200 A	$T_J = 25 \text{ }^\circ\text{C}$	1.13	V	
		400 A		1.46		
		200 A	$T_J = 125 \text{ }^\circ\text{C}$	0.75		
		400 A		0.89		
Maximum reverse leakage current per leg See fig. 2	$I_{RM}^{(1)}$	$T_J = 25 \text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	6	mA	
		$T_J = 125 \text{ }^\circ\text{C}$		85		
Maximum junction capacitance per leg	C_T	$V_R = 5 \text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz) $25 \text{ }^\circ\text{C}$		6000	pF	
Typical series inductance per leg	L_S	From top of terminal hole to mounting plane		5.0	nH	
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s	

Note

(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL CHARACTERISTICS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction temperature range	T_J	- 55	-	175	$^\circ\text{C}$
Maximum storage temperature range	T_{Stg}				
Thermal resistance, junction to case per leg	R_{thJC}	-	-	0.19	$^\circ\text{C/W}$
Thermal resistance, junction to case per module		-	-	0.095	
Thermal resistance, case to heatsink	R_{thCS}	-	0.10	-	
Weight		-	68	-	g
		-	2.4	-	oz.
Mounting torque		35.4 (4)		53.1 (6)	$\text{lbf} \cdot \text{in}$ (N · m)
Mounting torque center hole		30 (3.4)		40 (4.6)	
Terminal torque		30 (3.4)	-	44.2 (5)	
Vertical pull		-	-	80	$\text{lbf} \cdot \text{in}$
2" lever pull		-	-	35	



409CNQ...PbF Series

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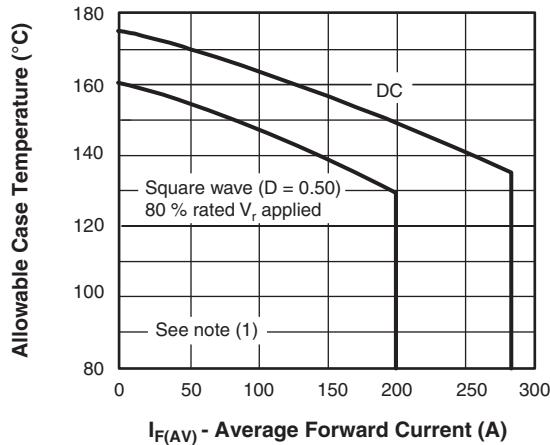


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

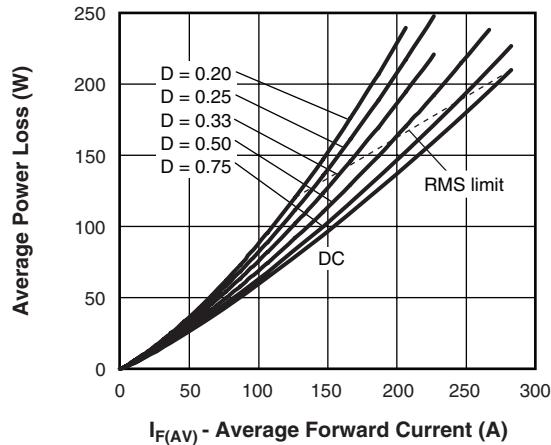


Fig. 6 - Forward Power Loss Characteristics

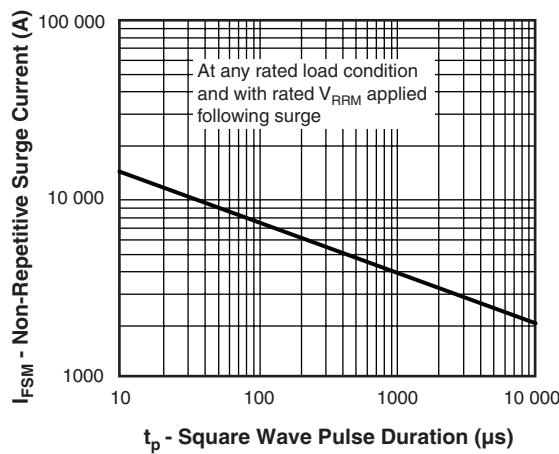


Fig. 7 - Maximum Non-Repetitive Surge Current

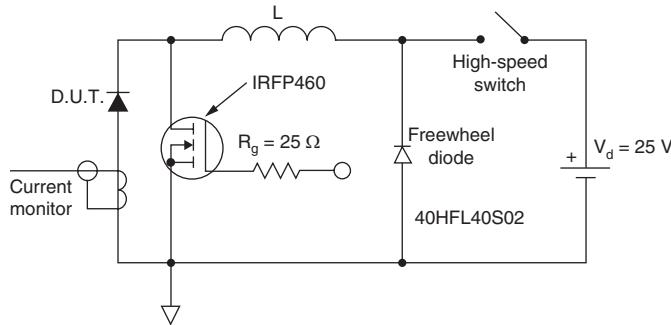


Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + Pd_{REV}) \times R_{thJC}$
- $P_d = \text{Forward power loss} = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- $Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

ORDERING INFORMATION TABLE

Device code	40	9	C	N	Q	135	PbF
	1	2	3	4	5	6	7

- | | |
|----------|----------------------------------|
| 1 | - Average current rating (x 10) |
| 2 | - Product silicon identification |
| 3 | - C = Circuit configuration |
| 4 | - N = Not isolated |
| 5 | - Q = Schottky rectifier diode |
| 6 | - Voltage ratings |
| 7 | - Lead (Pb)-free |
- 135 = 135 V
150 = 150 V